## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 7,220,489 B1 APPLICATION NO. : 10/826645

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DATED INVENTOR(S)

: May 22, 2007 : Chang Wei et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 5, line 43 " $SiO_xN_y$  layer 3201," should read --  $SiO_xN_y$  layer 3201, --.

Signed and Sealed this

Nineteenth Day of August, 2008

JON W. DUDAS
Director of the United States Patent and Trademark Office